

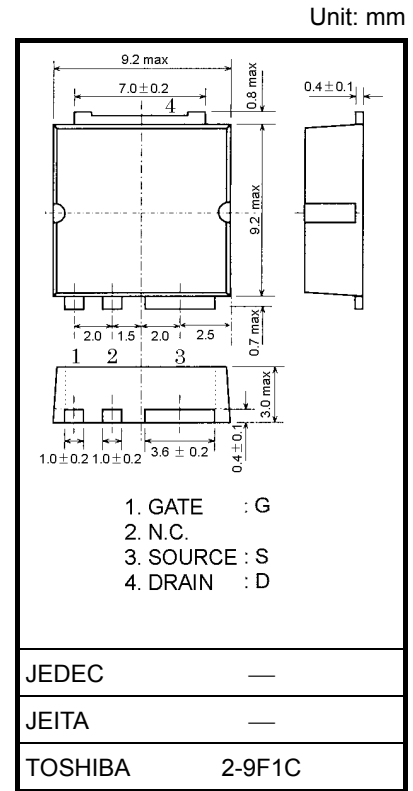
TK15X60U

Switching Regulator Applications

- Low drain-source ON resistance: $R_{DS(ON)} = 0.24$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 8.5$ S (typ.)
- Low leakage current: $I_{DSS} = 100 \mu A$ ($V_{DS} = 600$ V)
- Enhancement-mode: $V_{th} = 3.0\sim 5.0$ V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Absolute Maximum Ratings ($T_a = 25^\circ C$)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	600	V
Gate-source voltage		V_{GSS}	± 30	V
Drain current	DC (Note 1)	I_D	15	A
	Pulse ($t = 1$ ms) (Note 1)	I_{DP}	30	
Drain power dissipation ($T_c = 25^\circ C$)		P_D	125	W
Single pulse avalanche energy (Note 2)		E_{AS}	81	mJ
Avalanche current (Note 3)		I_{AR}	15	A
Repetitive avalanche energy		E_{AR}	12.5	mJ
Channel temperature		T_{ch}	150	$^\circ C$
Storage temperature range		T_{stg}	-55 to 150	$^\circ C$



Weight : 0.74 g (typ.)

Thermal Characteristics

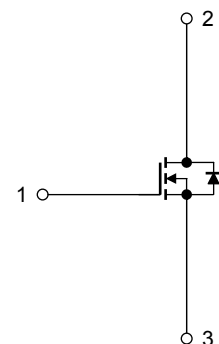
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	1.0	$^\circ C/W$

Note 1: Please use devices on conditions that the channel temperature is below $150^\circ C$.

Note 2: $V_{DD} = 90$ V, $T_{ch} = 25^\circ C$ (initial), $L = 0.63$ mH, $R_G = 25 \Omega$, $I_{AR} = 15$ A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.



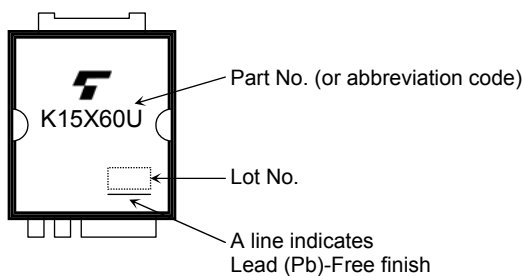
Electrical Characteristics (Ta = 25°C)

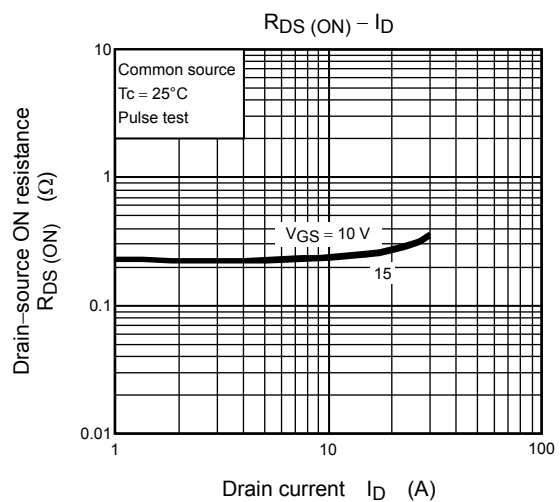
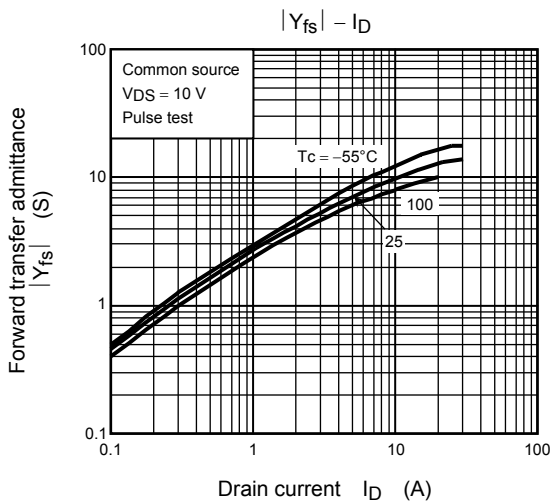
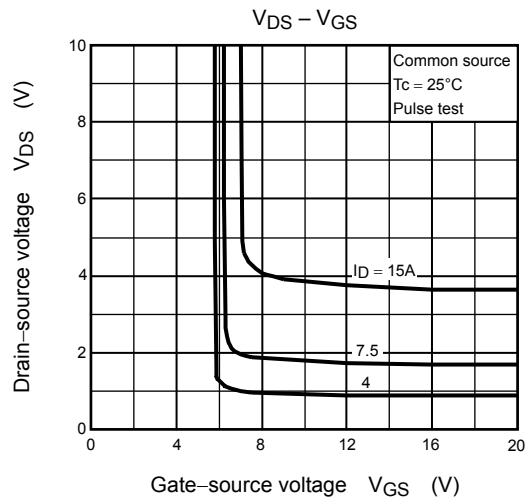
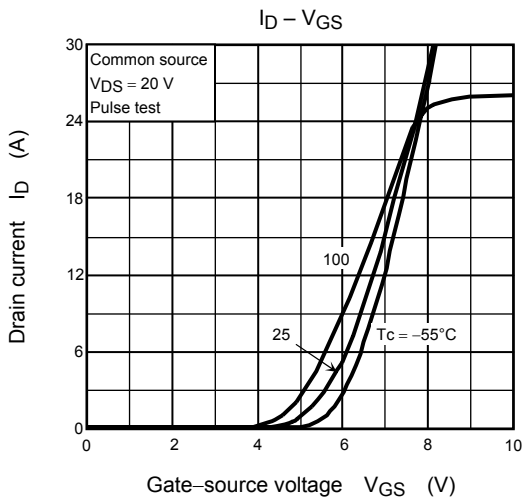
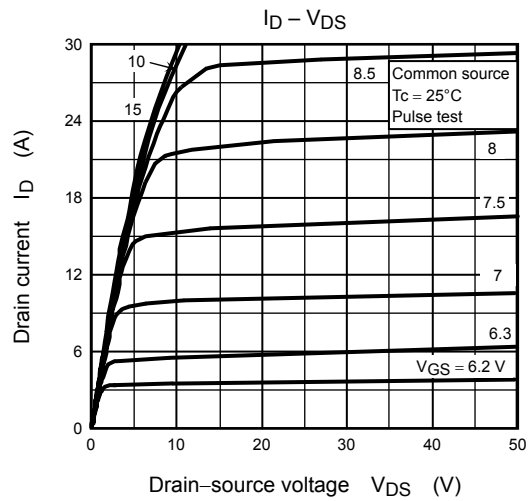
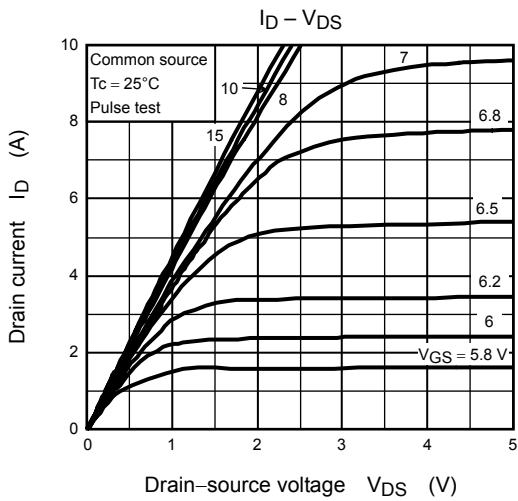
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 30\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 1	μA
Drain cut-off current		I_{DSS}	$V_{DS} = 600\text{ V}, V_{GS} = 0\text{ V}$	—	—	100	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	600	—	—	V
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	3.0	—	5.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 7.5\text{ A}$	—	0.24	0.3	Ω
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 7.5\text{ A}$	2.1	8.5	—	S
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	950	—	pF
Reverse transfer capacitance		C_{rss}		—	47	—	
Output capacitance		C_{oss}		—	2300	—	
Switching time	Rise time	t_r	<p>$I_D = 7.5\text{ A}$ $V_{GS} = 10\text{ V}$ $V_{DS} = 0\text{ V}$ $50\ \Omega$ $R_L = 40\ \Omega$ $V_{DD} \approx 300\text{ V}$</p>	—	37	—	ns
	Turn-ON time	t_{on}		—	80	—	
	Fall time	t_f		—	8	—	
	Turn-OFF time	t_{off}		Duty $\leq 1\%$, $t_w = 10\ \mu\text{s}$	—	105	
Total gate charge		Q_g	$V_{DD} \approx 400\text{ V}, V_{GS} = 10\text{ V}, I_D = 15\text{ A}$	—	17	—	nC
Gate-source charge		Q_{gs}		—	10	—	
Gate-drain charge		Q_{gd}		—	7	—	

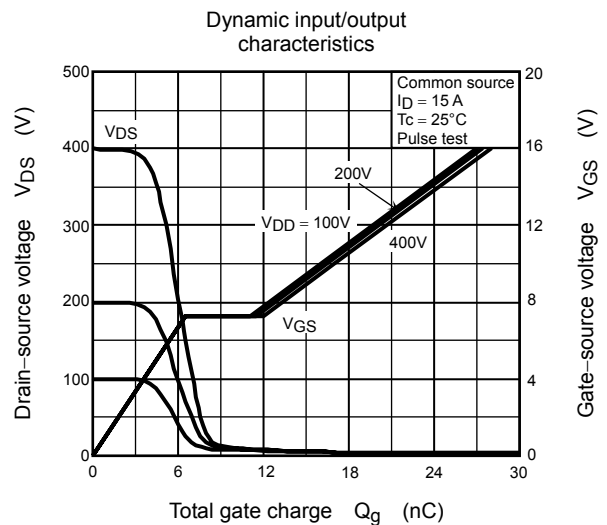
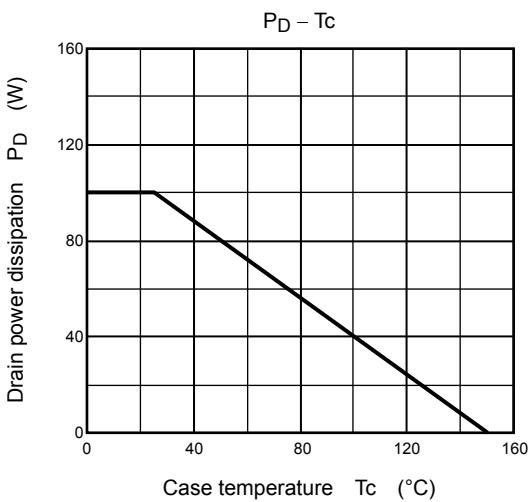
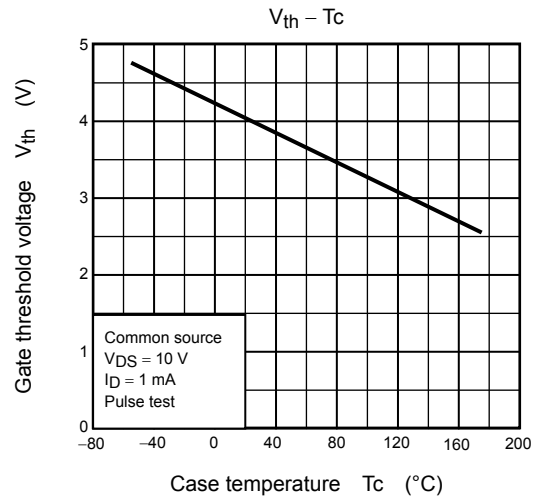
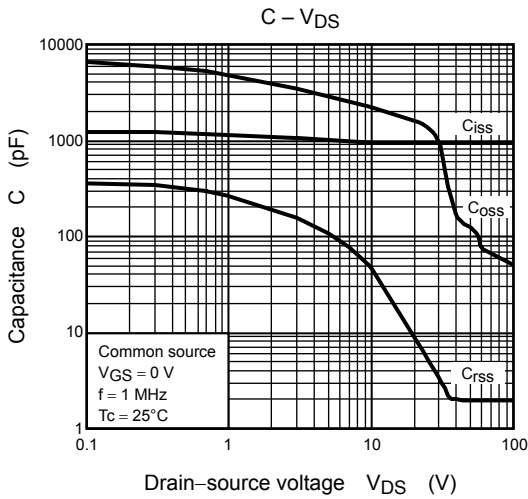
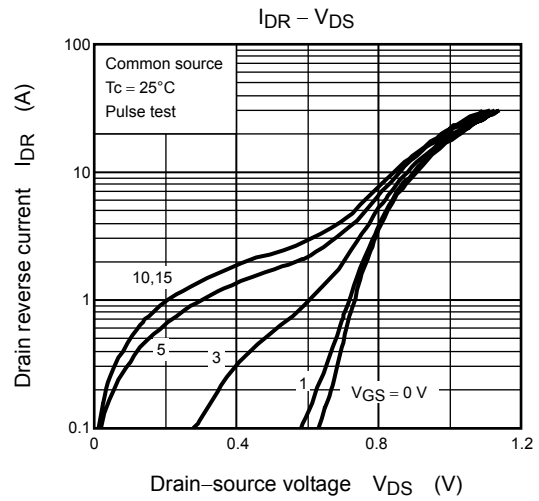
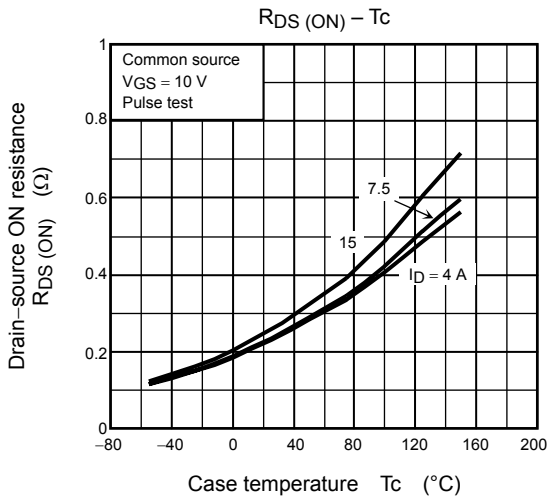
Source-Drain Ratings and Characteristics (Ta = 25°C)

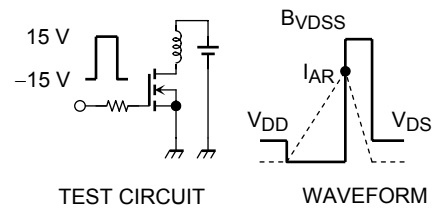
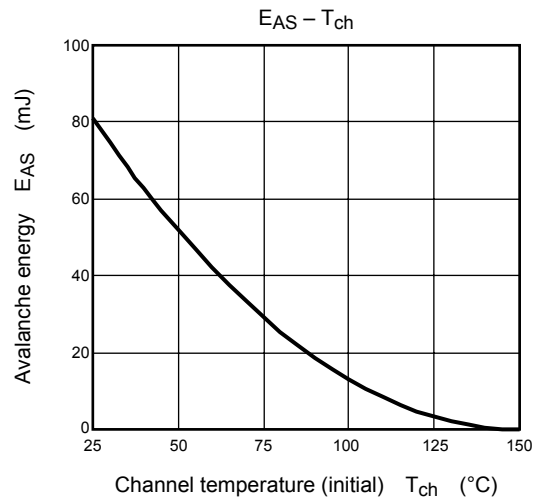
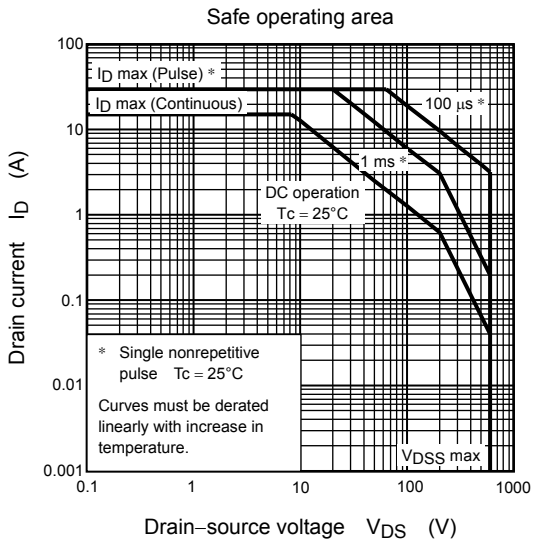
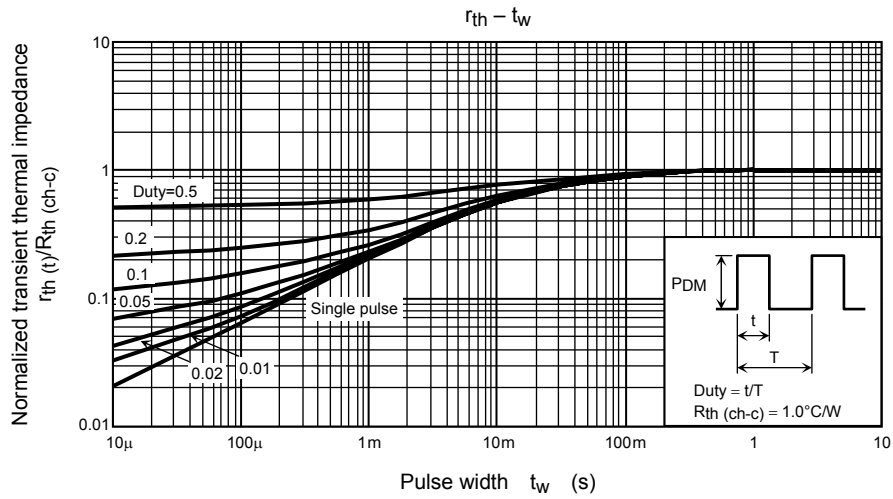
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)		I_{DR}	—	—	—	15	A
Pulse drain reverse current (Note 1)		I_{DRP}	—	—	—	30	A
Forward voltage (diode)		V_{DSF}	$I_{DR} = 15\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.7	V
Reverse recovery time		t_{rr}	$I_{DR} = 15\text{ A}, V_{GS} = 0\text{ V},$	—	530	—	ns
Reverse recovery charge		Q_{rr}	$dI_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	9.0	—	μC

Marking









$R_G = 25\ \Omega$
 $V_{DD} = 90\ V, L = 0.63\ mH$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I_{AR}^2 \cdot \left(\frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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